USN					

Fourth Semester B.E. Degree Examination, June/July 2015 Introduction to Material Science and Engineering

Time: 3 hrs. Max. Marks:100

> Note: Answer FIVE full questions, selecting at least TWO questions from each part.

		PART A	
1	a.	Explain about different types of material with their applications.	(10 Marks)
	b.	Write a brief note on the bonding and molecular interactions.	(10 Marks)
2	a.	What are unit cells? Explain the Bravais lattice of different crystal systems.	(10 Marks)
	b.	Describe briefly about the crystal structure of sodium chloride and diamond.	(10 Marks)
3	a.	What are dislocations? Mention the significance of dislocation.	(05 Marks)
	b.	What are surface defects? State the importance of defects.	(10 Marks)
	c.	Define slip. Explain the mechanism with factors affecting slip.	(05 Marks)
4	a.	Write a brief note on experimental diffraction methods.	(10 Marks)
	b.	State Bragg law. Derive an expression for constructive interference.	(10 Marks)
5	a. b. c. d.	PART – B What are phonons? Explain the phonon drag phenomenon. What is relaxation time? Derive an expression for relaxation time. Write a short note on impurity scattering. What is electrical conductivity? Explain about various factors affecting conductivity.	(05 Marks) (06 Marks) (04 Marks) electrical (05 Marks)
6	a.	State thermal conductivity. Derive the expression for thermal conductivity.	(10 Marks)
	b.	Write a brief note on thermoelectric effects on semiconductors.	(10 Marks)
7	a.	Explain about the mechanism of electronic polarization.	(08 Marks)
	Ъ.	Write a note on ionic polarization.	(06 Marks)
	c.	Derive an expression for dielectric loss.	(06 Marks)
8	a.	What is Hall effect? Explain the relationship between magnetic field and current d	•
	Ъ.	Explain the motion of electron in band theory.	(10 Marks) (10 Marks)
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